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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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2SK1859

Silicon N Channel MOS FET

REJ03G0981-0200
(Previous: ADE-208-1328)
Rev.2.00
Sep 07, 2005

Application

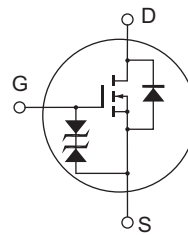
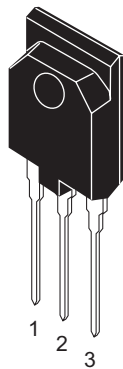
High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator

Outline

RENESAS Package code: PRSS0003ZA-A
(Package name: TO-3PFM)



1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DS}	900	V
Gate to source voltage	V_{GS}	± 30	V
Drain current	I_D	6	A
Drain peak current	$I_{D(pulse)}^{*1}$	15	A
Body to drain diode reverse drain current	I_{DR}	6	A
Channel dissipation	P_{ch}^{*2}	60	W
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1 \%$ 2. Value at $T_c = 25^\circ C$

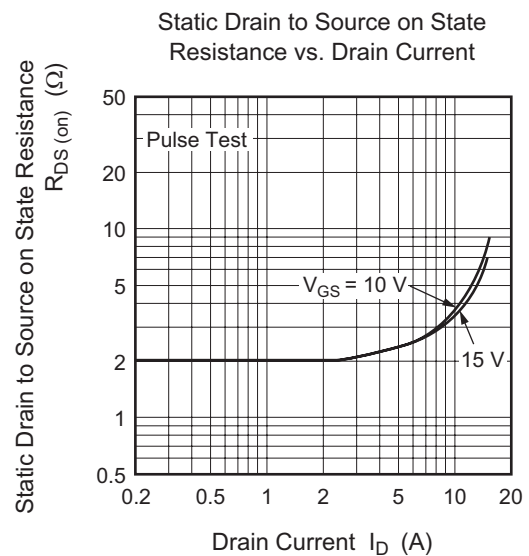
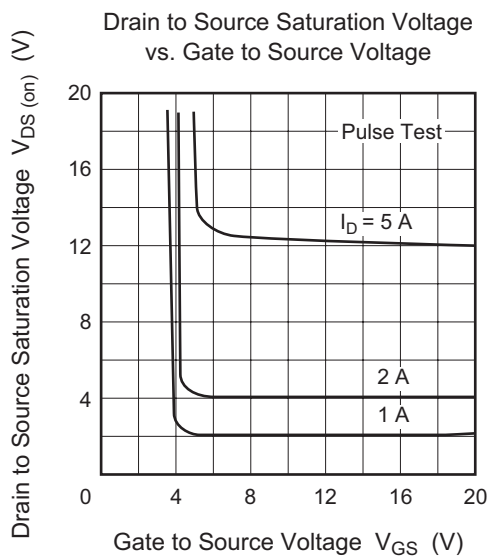
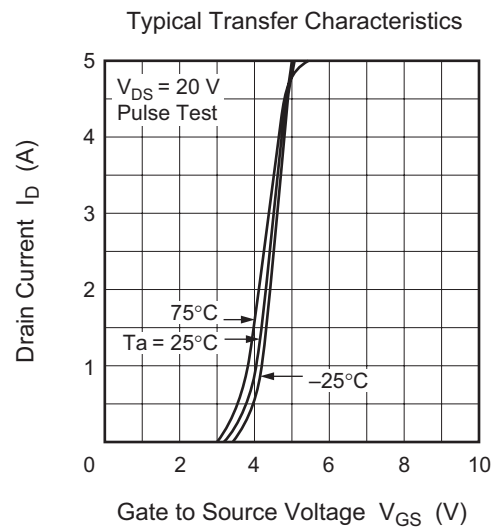
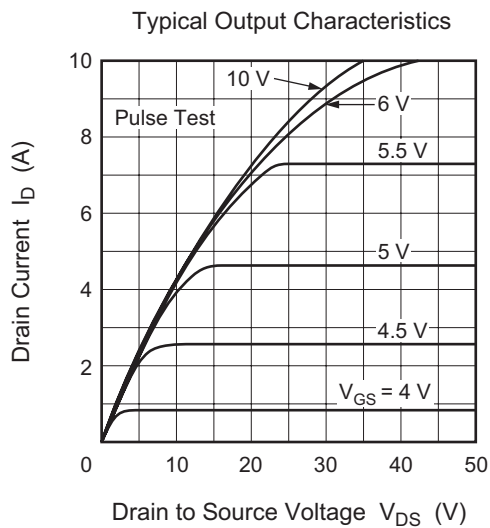
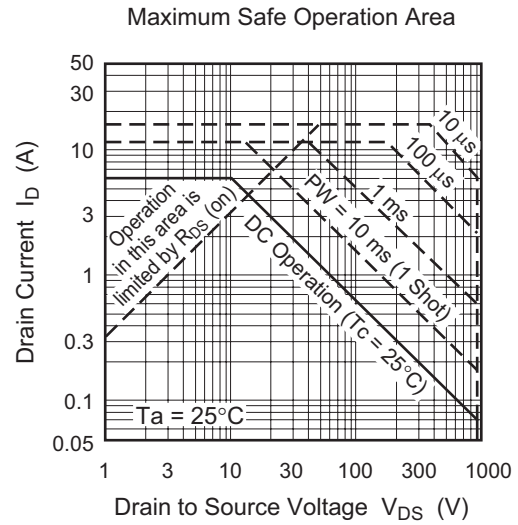
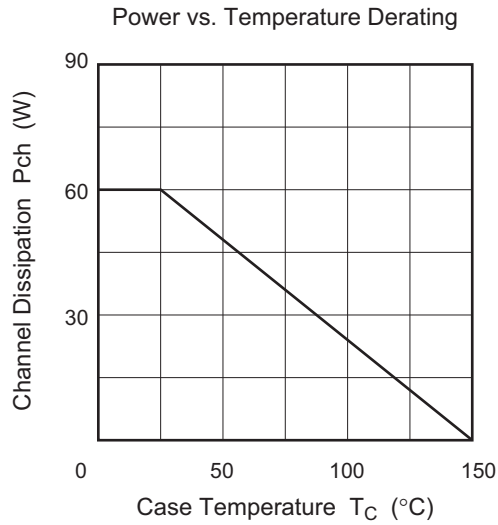
Electrical Characteristics

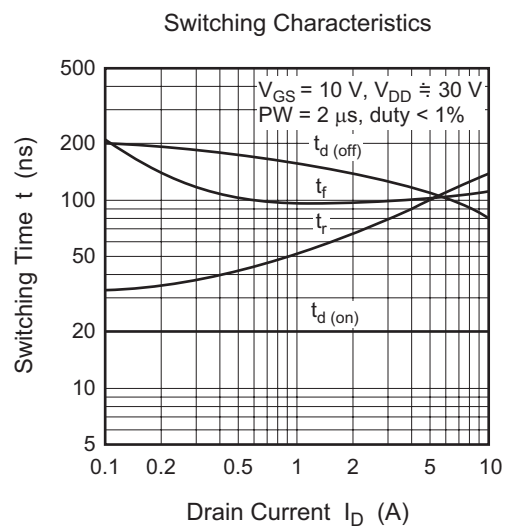
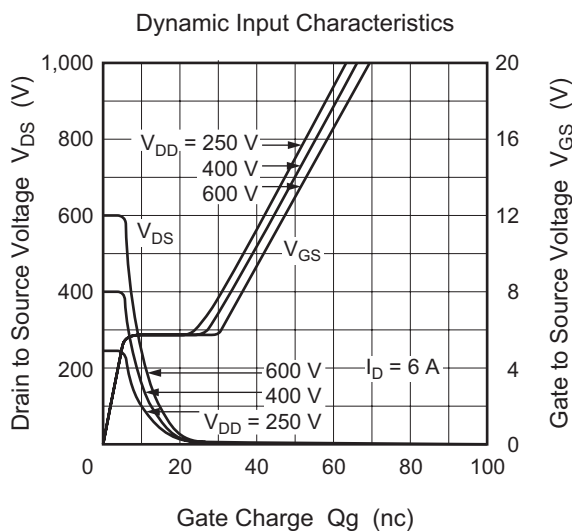
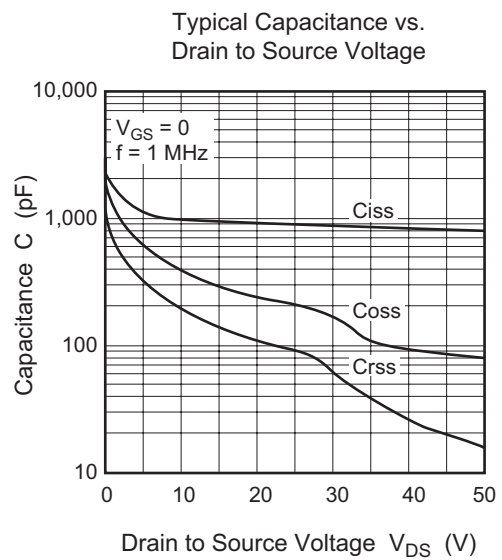
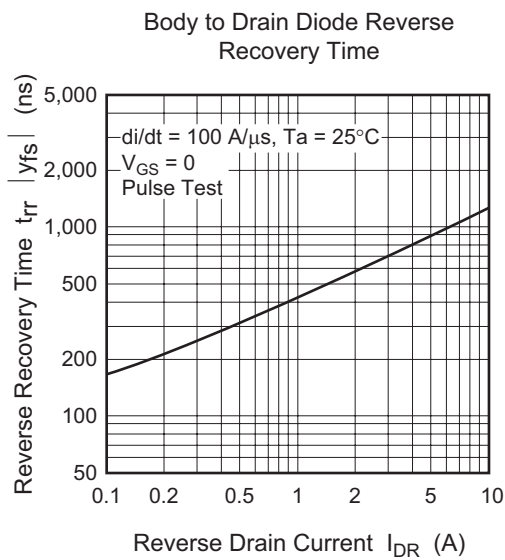
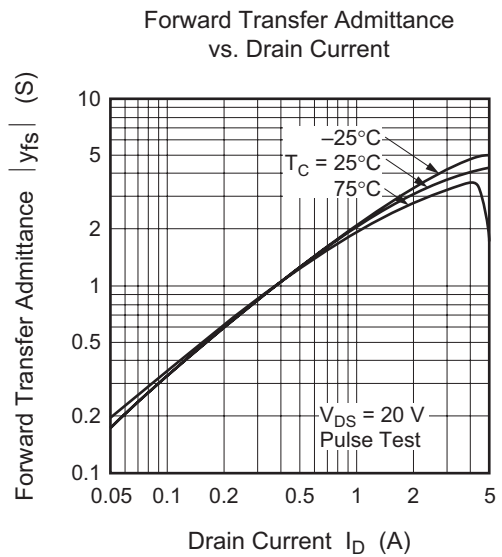
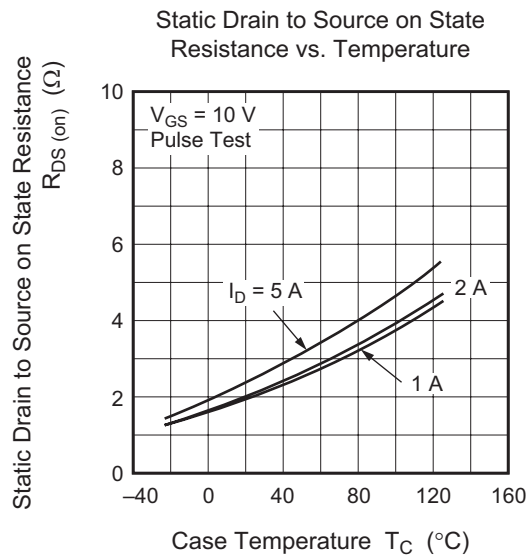
(Ta = 25°C)

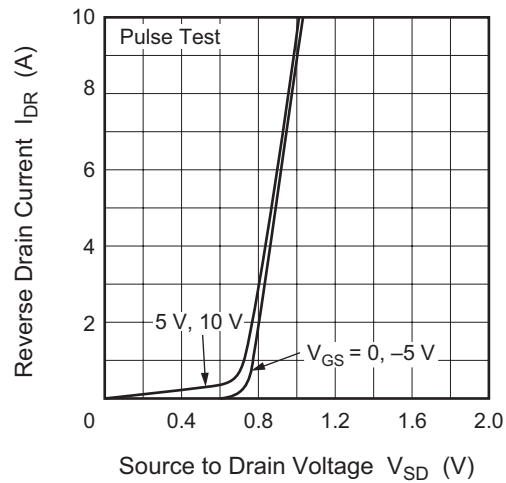
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	900	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 30	—	—	V	$I_G = \pm 100 \mu A$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 25 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	250	μA	$V_{DS} = 720 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	2.0	3.0	Ω	$I_D = 3 \text{ A}$, $V_{GS} = 10 \text{ V}^{*3}$
Forward transfer admittance	$ y_{fs} $	2.3	3.7	—	S	$I_D = 3 \text{ A}$, $V_{DS} = 20 \text{ V}^{*3}$
Input capacitance	C_{iss}	—	980	—	pF	$V_{DS} = 10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	400	—	pF	
Reverse transfer capacitance	C_{rss}	—	195	—	pF	
Turn-on delay time	$t_{d(on)}$	—	20	—	ns	$I_D = 3 \text{ A}$, $V_{GS} = 10 \text{ V}$, $R_L = 10 \Omega$
Rise time	t_r	—	80	—	ns	
Turn-off delay time	$t_{d(off)}$	—	125	—	ns	
Fall time	t_f	—	100	—	ns	
Body to drain diode forward voltage	V_{DF}	—	0.9	—	V	$I_F = 6 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	1000	—	ns	$I_F = 6 \text{ A}$, $V_{GS} = 0$, $di_F/dt = 100 \text{ A}/\mu s$

Note: 3. Pulse Test

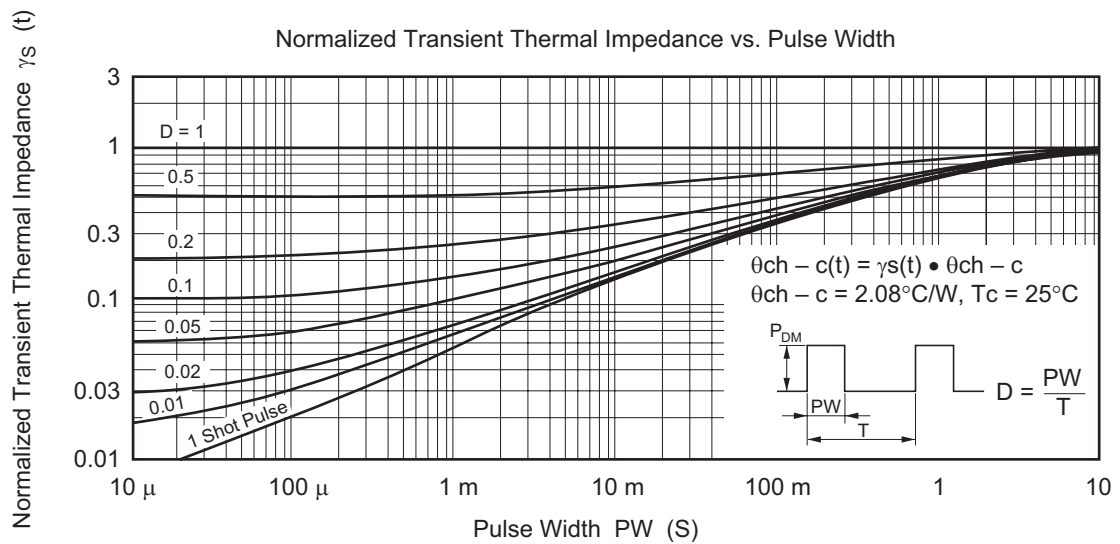
Main Characteristics



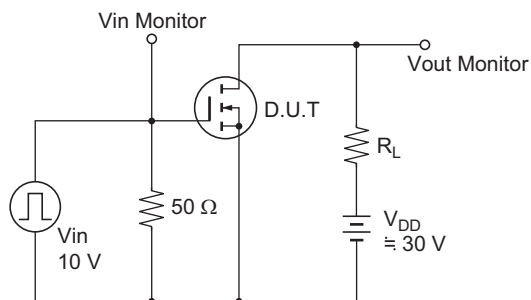


Reverse Drain Current vs.
Source to Drain Voltage

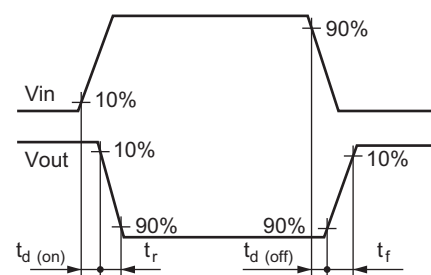
Normalized Transient Thermal Impedance vs. Pulse Width



Switching Time Test Circuit



Waveforms



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